

SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

CPH5504

NPN Epitaxial Planar Silicon Transistor **High-Current Switching Applications**

Applications

• DC-DC converter, relay drivers, lamp drivers, motor drivers, flash.

Features

- Composite type with 2 NPN transistors in one package facilitating high-density mounting.
- The CPH5504 is composed of 2 chips each equivalent to the CPH3205.
- Ultrasmall package facilitates miniaturization in end products. (mounting height : 0.9mm)

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		100	V
Collector-to-Emitter Voltage	VCES		100	V
Collector-to-Emitter Voltage	VCEO		50	V
Emitter-to-Base Voltage	VEBO		6	V
Collector Current	IC		3	Α
Collector Current (Pulse)	ICP		6	A
Base Current	IB		600	mA
Collector Dissipation	PC	Mounted on a ceramic board (600mm ² X0.8mm)	0.9	W
Total Power Dissipation	PT	Mounted on a ceramic board (600mm ² X0.8mm)	1.2	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +15	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} =40V, I _E =0A			1	μΑ
Emitter Cutoff Current	IEBO	VEB=4V, IC=0A			1	μΑ
DC Current Gain	hFE1	V _{CE} =2V, I _C =100mA	200		560	
	hFE2	V _{CE} =2V, I _C =3A	70			
Gain-Bandwidth Product	fT	VCE=10V, IC=500mA		380		MHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		13		pF
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)	IC=1A, IB=50mA		80	120	mV
		IC=2A, IB=100mA		140	210	mV
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	IC=2A, IB=100mA		0.88	1.2	V
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Marking : ED

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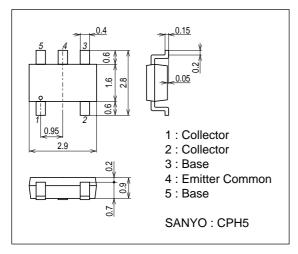
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =10μA, I _E =0A	100			V
Collector-to-Base Breakdown Voltage	V(BR)CES	IC=100μA, RBE=0Ω	100			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=1mA, RBE=∞	50			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =10μΑ, I _C =0Α	6			V
Turn-ON Time	ton	See specified Test Circuit.		35		ns
Storage Time	tstg	See specified Test Circuit.		300		ns
Fall Time	tf	See specified Test Circuit.		22		ns

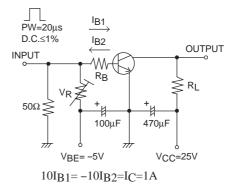
Package Dimensions

unit : mm

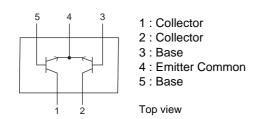
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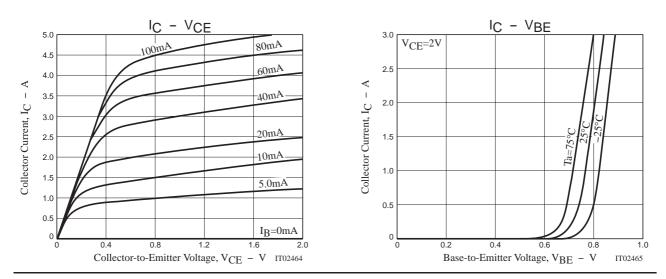


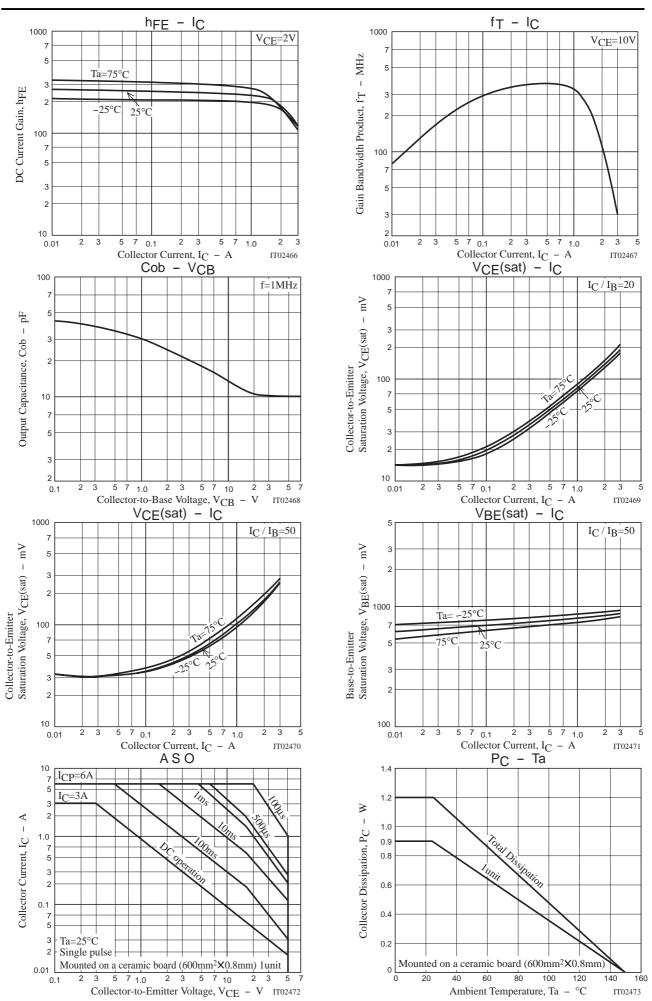
Switching Time Test Circuit

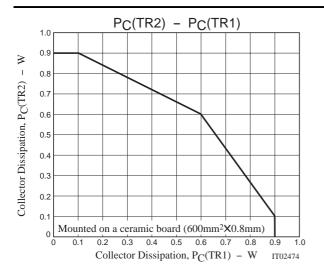


Electrical Connection









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